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density functional with tests for weakly bound systems:
$$\mathbf{r}^2 \mathbf{V}(\mathbf{r})$$

$$\mathbf{r}^2 \mathbf{V}(\mathbf{r}) = \mathbf{r}^2 \mathbf{V}(\mathbf{r}) + \mathbf{r}^2 \mathbf{V}(\mathbf{r})$$

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Phys. Rev. B **106**, 075422 — Published 23 August 2022

DOI: [10.1103/PhysRevB.106.075422](https://doi.org/10.1103/PhysRevB.106.075422)

1 Workhorse minimally-empirical dispersion-corrected density functional, with tests for 2 weakly-bound systems: r²SCAN+rVV10

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12 (Dated: July 25, 2022)

SCAN+rVV10 has been demonstrated to be a versatile van der Waals (vdW) density functional that delivers good predictions of both energetic and structural properties for many types of bonding. Recently, the r²SCAN functional has been devised as a revised form of SCAN with improved numerical stability. In this work, we refit the rVV10 functional to optimize the r²SCAN+rVV10 vdW density functional, and test its performance for molecular interactions and layered materials. Our molecular tests demonstrate that r²SCAN+rVV10 outperforms its predecessor SCAN+rVV10 in both efficiency (numerical stability) and accuracy. This good performance is also found in lattice-constant predictions. In comparison with benchmark results from higher-level theories or experiments, r²SCAN+rVV10 yields excellent interlayer binding energies and phonon dispersions for layered materials.

13 I. INTRODUCTION

14 Quantum fluctuations in the electronic density give rise
15 to instantaneous dipole moments, making van der Waals
16 (vdW) or London dispersion interactions ubiquitous in
17 electronic matter. Despite its relative small strength, the
18 ubiquitous vdW force plays a fundamental role in diverse
19 fields of both science and industry: from structural bi-
20 ology and polymer science, to nanotechnology and sur-
21 face science. It participates in the structural evolution of
22 DNA¹, proteins², and many other complex molecules and
23 their interactions³, and hence the origination⁴ and phys-
24 ical activities of living beings. The vdW forces are also
25 crucial for the surface and interfacial reactions controlling
26 artificial and natural catalytic⁵⁻⁷ and corrosion reactions
27 on alloy surfaces⁸. The vdW interactions are even found
28 to be necessary for accurate descriptions of some densely
29 packed systems, suggesting that vdW forces are not as
30 negligible for normal solids as commonly thought⁹⁻¹¹.

31 While vdW interactions are fully captured in the exact
32 density functional theory (DFT)¹², their non-local nature
33 means they (or at least their most long-ranged parts)
34 are missed by semi-local exchange-correlation (XC) den-
35 sity functional approximations (DFAs) like the local
36 density approximation (LDA), generalized gradient ap-
37 proximation (GGA), or meta-GGA. Despite this lim-
38 itation, semi-local DFAs are the mainstay of modern
39 first-principles electronic structure modelling, achieving
40 useful accuracy at reasonable cost. While higher-level
41 methods that fully account for vdW forces, such as
42 quantum Monte Carlo (QMC)¹³, coupled-cluster singles
43 and doubles with perturbative triples CCSD(T)¹⁴, and
44 the adiabatic-connection fluctuation-dissipation theorem
45 within the random-phase approximation (RPA)¹⁵, can

46 provide benchmark references, their poor scaling with
47 system size prohibits large-scale applications. Instead, a
48 practical choice for improving accuracy is to include vdW
49 interactions in the DFT framework as a modification or
50 correction to a semi-local XC approximation. Common
51 approaches include the DFT+D series¹⁶⁻¹⁹, Tkatchenko-
52 Scheffler (TS) methods²⁰⁻²², the Rutgers-Chalmers vdW-
53 DF family²³, Vydrov-van Voorhis (VV10)²⁴, rVV10²⁵
54 density functionals, and the Becke-Johnson exchange
55 hole model^{26,27}. We should also mention the damped-
56 Zaremba-Kohn (dZK)^{28,29} correction, which requires
57 many material-dependent input parameters.

58 The performance of the vdW-corrected DFA depends
59 upon both the semi-local XC and vdW functionals. A
60 good example for this case is the SCAN+rVV10 vdW
61 functional. The strongly constrained and appropriately
62 normed (SCAN) meta-GGA³⁰, satisfies all known 17 ex-
63 act constraints applicable to a meta-GGA, and has shown
64 good accuracy for diverse bonding environments³¹. It has
65 been demonstrated that SCAN includes a portion of the
66 intermediate range of vdW interactions, which rational-
67 izes its excellent predictions of structural and energetic
68 properties of water³¹. The rVV10 non-local vdW den-
69 sity functional²⁵ requires only the electron density and
70 its first derivatives as inputs, and contains two empirical
71 parameters, C and b . The final SCAN+rVV10 vdW den-
72 sity functional has been demonstrated to work for gen-
73 eral geometries, and achieves an accuracy comparable to
74 that of higher-level methods like RPA and CCSD(T) for
75 various vdW benchmark systems, while scaling more fa-
76 vorably with system size³².

77 Despite these successes, SCAN exhibits undesirable
78 numerical problems^{33,34} that harm its computational ef-
79 ficiency and can prevent the self-consistent field process

from converging. To achieve high accuracy for diverse systems, SCAN interpolates between single-orbital and slowly-varying energy densities using a variable α (defined in Ref. 30) that is sensitive to the local chemical environment. α partly contributes to the numerical instability of SCAN³³.

Moreover, SCAN’s inclusion of intermediate vdW interactions can be a hindrance when combined with non-local dispersion corrections. SCAN predicts quantitatively correct lattice parameters for the layered solid PPTA, whereas SCAN+rVV10 strongly overbinds within layers, yielding a much too-small a -parameter³⁵. SCAN’s tendency to overbind hydrogen-bound molecules is worsened in both SCAN+rVV10 and SCAN+D3^{36–38}. When evaluated on the Hartree-Fock density (a kind of “density correction”), SCAN provides a chemically accurate description of liquid water, whereas dispersion-corrected variants of SCAN still overbind³⁹.

The rSCAN meta-GGA³⁴ modifies SCAN to successfully improve numerical stability, but at the price of reduced accuracy^{40–42}. To remove the divergence in the derivatives of α in single orbital regions ($\alpha \rightarrow 0$),³³ rSCAN uses a regularized α' that breaks exact coordinate scaling conditions^{43–45} and the uniform density limit obeyed by SCAN. To remove oscillations in the exchange-correlation potential of SCAN induced by the function of α that interpolates between energy densities, rSCAN uses a smooth polynomial for the chemically-relevant range $0 \leq \alpha \leq 2.5$. This choice introduces spurious terms in the slowly-varying ($\alpha \approx 1$) density-gradient expansion that deviate from the exact expansion^{46,47} recovered by SCAN.

These shortcomings are remedied by the r²SCAN meta-GGA⁴⁸, which modifies the rSCAN regularizations to obey almost every exact constraint SCAN does. (A higher-order density-gradient expansion for exchange is recovered by SCAN⁴⁹.) The satisfaction of exact constraints and greater smoothness of r²SCAN preserves the accuracy of SCAN and numerical efficiency of rSCAN^{19,42,48,50}, permitting construction of meta-GGA pseudopotentials⁵¹. Therefore, we expect r²SCAN to be a better candidate for the rVV10 correction.

It should be noted that a variant of r²SCAN with a long range D4¹⁸ dispersion correction was recently published.¹⁹ r²SCAN+D4 more realistically describes non-covalent and hydrogen-bound systems than SCAN+D4,¹⁹ suggesting that r²SCAN includes less of the intermediate vdW interaction than SCAN. Reference 19 presented a fitted value $b = 12.3$ for r²SCAN+VV10 (not rVV10). rVV10 was designed to perform like VV10, but at a lower computational cost in plane-wave basis set codes. We now motivate why an r²SCAN+rVV10 is needed when a highly-accurate r²SCAN+D4 exists.

The D and VV10 series of vdW corrections are complementary approaches for describing long-range vdW interactions in real systems. Both corrections have empirical parts, with the VV10 series requiring two material-independent empirical parameters, and D4 requiring

three parameters in its damping function. The D4 dispersion coefficients are computed on-the-fly from tabulated material-dependent data like the atomic polarizabilities and Mulliken partial charges¹⁸. rVV10 is conceptually simpler than D4 and its reliance on fewer empirical parameters makes it an appealing alternative to D4 for solid-state physics, though both methods find common use. In a comparison⁵² of 243 non-covalent cluster interactions, SCAN-D3 and SCAN+rVV10 had comparable root mean square deviations from reference values.

The original VV10²⁴ and subsequent rVV10²⁵ vdW corrections differ in subtle ways. The VV10 kernel is a two-point function, and its evaluation requires a double integral over real space. Such a correction is challenging to implement in plane-wave codes because of the high numeric cost of this double integral. The rVV10 kernel approximates the VV10 kernel by interpolation over a set of grid points, drastically reducing the computational overhead in plane-wave basis set codes.

When rVV10 is a good approximation to VV10, the b parameters should not differ substantially. We confirm this interpretation here. However, a VV10-corrected DFA which tends to overbind molecules is expected⁵³ to further overbind when combined with rVV10 using the same b parameter. When using the same b parameter, the most pronounced differences between VV10 and rVV10 occur in low-density regions⁵⁴. However, the dispersion correction to a meta-GGA like SCAN or r²SCAN should be most meaningful in these low-density regions.

A limitation of the VV10 and rVV10 long-range dispersion corrections is that they can describe only two-body interactions between volume elements, ignoring the three-body Axilrod-Teller⁵⁵ effects. Here we fit the b parameters in those corrections to the binding energy curve of the Ar dimer, in which the conventional many-body expansion stops at the two-body term.

The vdW interactions are crucial in shaping the structure and properties of 2D/layered materials. Such materials have seen renewed interest since the exfoliation of graphene in 2004⁵⁶, and have nurtured new applications promising the next generation of information technology devices⁵⁷. As such, we test the newly determined b parameter for r²SCAN+rVV10 on standard sets, with a focus on layered materials properties.

II. METHODS

A. Parameters in r²SCAN+rVV10

The rVV10^{24,25} non-local correlation functional is similar in construction to the Rutgers–Chalmers vdW-DF family²³,

$$E_c^{\text{nl}} = \int d\mathbf{r} n(\mathbf{r}) \left[\frac{\hbar}{2} \int d\mathbf{r}' \phi(\mathbf{r}, \mathbf{r}') n(\mathbf{r}') + \beta \right]. \quad (1)$$

β vanishes for the Rutgers–Chalmers vdW-DFs, and the XC functional reads as

$$E_{xc} = E_{xc}^0 + E_c^{nl}. \quad (2)$$

Here, $n(\mathbf{r})$ is the electron density, $\phi(\mathbf{r}, \mathbf{r}')$ is the density-density interaction kernel, and E_{xc}^0 is the semi-local exchange correlation functionals to be corrected. $\beta = (3/b^2)^{3/4}/32$ in Hartree is required for zero E_c^{nl} for the uniform electron gas. Two empirical dimensionless parameters C and b appear in the kernel $\phi(\mathbf{r}, \mathbf{r}')$: C is adjusted to recover the accurate $-C_6/R^6$ asymptotic vdW interaction between molecules at large separation R , and b controls the damping of E_c^{nl} at short range.

The original VV10 and rVV10 functionals^{24,25} were combined with the semi-local XC functional^{58,59} $E_{xc}^0 = E_x^{\text{rPW86}} + E_c^{\text{PBE}}$, partly due to the near absence of vdW in rPW86 exchange⁵⁹. (For a discussion of how intermediate-range vdW can arise from semilocal exchange, see Ref. 32.) For a semi-local E_{xc}^0 , $C = 0.0093$ was recommended²⁴, and the b parameter was determined as 5.9 and 6.3 by fitting to the interaction energies of the S22 set^{60,61} for the original VV10 and rVV10, respectively. Increasing C or b generally results in a smaller vdW correction. There is a conventional many-body expansion⁶² of the dispersion interaction within a collection of bodies (atoms or molecules) that includes two-body and higher-order many-body effective interactions. By construction, the VV10 and rVV10 long-range corrections explicitly account for only pairwise interactions between volume elements. The Ar dimer has only conventional two-atom interactions, whereas the S22 has many-atom interactions. Fitting rVV10 to systems with many-atom interactions would average over the two- and many-atom interactions⁶³.

Here, we refit $b = 11.95$ for r²SCAN+rVV10 by adjusting it to best recover the binding-energy curve of the argon dimer with bond lengths between 3.5 and 6.0 Å, as shown in Fig. 1(a). Using the r²SCAN+VV10 (MAE 0.32 kcal/mol for S22⁶⁶) value $b = 12.3$ ¹⁹, the mean absolute error (MAE) in the binding energy curve of Ar₂ increases negligibly by 0.2 meV (0.0046 kcal/mol). Note that r²SCAN-D4 makes a 0.29 kcal/mol MAE on the S22 set⁶⁶, virtually identical to both variants of r²SCAN+rVV10.

B. Computational details

The DFT calculations in this work were performed using the Vienna Ab initio Simulation Package (VASP)⁶⁷ version 5.4.4, with user corrections for the meta-GGA correlation potential in spin-unrestricted calculations, and to the rVV10 stress tensor⁶⁸. For computational details of the Ar dimer binding-energy curve, the S22 molecular interaction energies^{60,61,69}, and the L28 layered material database⁷⁰, refer to the the original publication of SCAN+rVV10³², with the following adjustments. We follow the practice³² of using hard pseudopo-

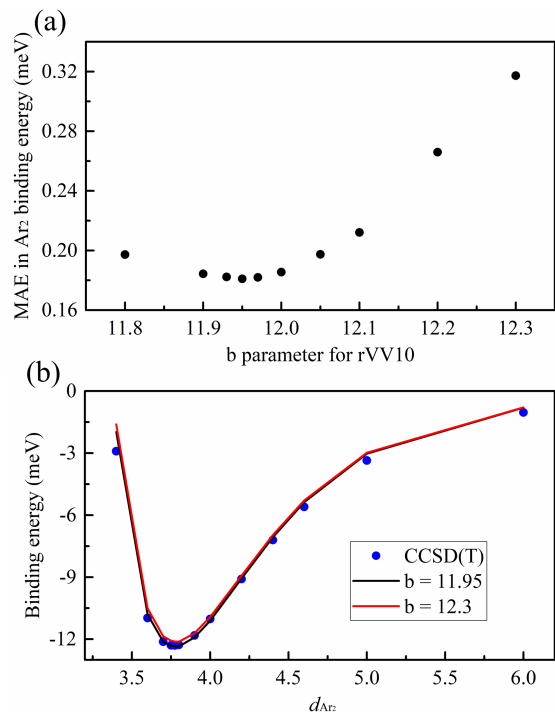


FIG. 1. (a) Mean absolute error of the Ar dimer binding energy as a function of the b parameter in r²SCAN+rVV10. (b) The binding curve for Ar dimer from r²SCAN+rVV10 (red solid line) compared to CCSD(T) curve^{64,65} as the reference (blue dots) as a function of their separation d_{Ar_2} in Å.

tentials for the S22 set, due to their better accuracy for molecules with short bonds, and as recommended by the VASP manual⁶⁷. All input and output files for the Ar₂, S22, and L28 calculations can be found at the public code repository⁷¹.

Error statistics for the inter-layer binding energies and lattice parameters of the L28 set are presented in Tables II and III. Values for individual solids are presented in Tables VIII and IX of the Appendix. The same methods used to validate SCAN+rVV10³² are used here for calculation of the L28 binding energies (compared to reference RPA⁷² calculations): the intra-layer lattice constants were fixed to their experimental values, and the inter-layer lattice constants were relaxed only for the bulk structures. Only atomic coordinates were relaxed for the mono-layer model, as in the RPA calculations. The calculated lattice constants in Tables II, III, VIII and IX are from full relaxations.

Non-magnetic ground states were used in the current calculations for these compounds, except the three vanadium-based compounds, where a ferromagnetic ordering was used instead. For the SCAN+rVV10 and r²SCAN+rVV10 results in Table IV, intra-layer lattice constants were also relaxed for the bulk and mono-layer models, although the difference in binding energy was negligible. For the phonon calculations of graphite and MoS₂, we used the Phonopy code⁷³ to obtain the harmonic force constants from VASP atomic force calcula-

tions within the finite displacement method (0.015 Å).
 For solid poly(*p*-phenylene terephthalamide) (PPTA),
 k -point spacing of 0.15 Å⁻¹ (yielding a $6 \times 9 \times 4$ k -grid),
 and a plane-wave cutoff of 900 eV were used.

III. RESULTS AND DISCUSSIONS

A. Dispersion interactions in molecules

To evaluate the performance of r²SCAN+rVV10 with
 the newly fit $b = 11.95$, we tested it on both molecu-
 lar systems (S22 data set) and layered materials. We
 are especially interested in the efficiency and accuracy
 of r²SCAN+rVV10, in comparison with its predecessor
 SCAN+rVV10.

We assessed the accuracy of SCAN+rVV10 and
 r²SCAN+rVV10 predicted interaction energies for the
 S22 molecular complexes data set. The S22 set in-
 cludes seven hydrogen-bonded, eight dispersion-bound,
 and seven mixed-binding complexes. Table I presents the
 error statistics of SCAN+rVV10 and r²SCAN+rVV10
 for the S22 set, relative to CCSD(T) benchmarks⁶⁹.
 Table VII of the Appendix complements Table I, pre-
 senting values for each molecule in the S22 set, and
 comparing our SCAN+rVV10 and r²SCAN+rVV10 re-
 sults with Perdew-Burke-Ernzerhof (PBE)⁵⁸, SCAN, and
 vdW-DF2⁷⁴ predictions.

To further demonstrate the improved numeric stabil-

ity of r²SCAN over SCAN, we also present results using
 smaller grid sizes in these tables. Two parameters, EN-
 CUT and ENAUG, control the size of the plane-wave
 basis sets used by VASP. A plane-wave basis set offers
 a systematic approach to converged total energies by
 adding more reciprocal lattice vectors \mathbf{G} to the set. EN-
 CUT (in eV) controls how many \mathbf{G} are used to repre-
 sent the valence electron density by accepting only those
 $|\mathbf{G} + \mathbf{k}|^2 < 2(\text{ENCUT})$ for each \mathbf{k} -point. In the pseudopo-
 tential approach used by VASP, the potential due to core
 states is represented by a non-local potential within an
 “augmentation” radius. ENAUG controls the number of
 \mathbf{G} used to represent the orbitals within the augmenta-
 tion radius, in the same fashion as ENCUT. We have
 noticed a strong sensitivity of SCAN-like meta-GGAs to
 the ENAUG setting, which we have set at an appropri-
 ately high value (2000 eV) to ensure well-converged re-
 sults. Similar grid sensitivities were noted⁷⁵ for SCAN
 and SCAN + rVV10 applied to different arrangements of
 the benzene dimer. Note also that VASP permits com-
 pilation with a precompiler flag, DnoAugXCmeta, that
 does not use the augmented charge density in meta-GGA
 calculations. That flag was not used in this work.

With the refit $b = 11.95$, r²SCAN+rVV10 outperforms
 SCAN+rVV10 in all three subgroups and overall for the
 S22 binding energy database, and has an accuracy com-
 petitive with the original rVV10 functional. When com-
 pared to its excellent performance for dispersion-bound
 and mixed complexes, though improvement is notewor-
 thy, r²SCAN+rVV10 still tends to over-bind hydrogen-
 bonded systems. This is rationalized as a density-driven
 error, rather than an error inherent to rVV10. For ex-
 ample, the hydrogen-bonded water dimer is over-bound
 by 0.44 kcal/mol or 9% in SCAN, and this error is re-
 duced to 0.13 kcal/mol when SCAN is applied to the
 more accurate Hartree-Fock electron density, and not to
 its own self-consistent density⁷⁶. That fact speaks for
 fitting the b parameter of rVV10 to the binding energy
 curve of the Ar dimer (as done here) or to the eight
 dispersion-bound complexes in S22, and not to the whole
 S22 set. For the eight dispersion-bound complexes of
 S22, r²SCAN+rVV10 is quite accurate (see Table I).
 The superior numerical performance of r²SCAN over
 SCAN is consistent with other works studying molecu-
 lar systems⁴⁸, lattice dynamics of solid-state systems⁷⁷,
 and in combination with the D4 vdW functional¹⁹.

Column (d) of Table I presents the S22 error scores
 of r²SCAN+rVV10 with the VV10 value $b = 12.3$. The
 0.0–0.04 kcal/mol differences in the converged S22 mean
 absolute errors (MAEs) using both b parameters are com-
 parable to the error in the reference CCSD(T) values,
 which used⁶⁹ small triple- ζ grids. Thus we cannot defini-
 tively say that one value of b is better for describing com-
 mon noncovalent interactions. The method¹⁸ that fitted
 $b = 12.3$ used larger sets of dispersion-bound dimers as
 a function of the inter-monomer separation, yet yields
 essentially the same average errors as $b = 11.95$, fitted
 to the Ar dimer. As explicated in Ref. 53, we advo-

TABLE I. Mean errors (ME, kcal/mol) and mean absolute errors (MAE, kcal/mol) in the unsigned interaction energies of the S22 data set, taken with respect to CCSD(T) results⁶⁹. Different (ENCUT, ENAUG) settings (described in Section III A) are tested for r²SCAN+rVV10 and SCAN+rVV10; both values are in eV. Users who need less accuracy can use lower settings. Table VI in the Appendix presents S22 data for another (ENCUT, ENAUG) setting intermediate to those shown here, as well as percentage errors. Table VII in the Appendix presents interaction energies for each molecule in the S22 set, the CCSD(T) reference values, as well as values for other density functional approximations.

	SCAN + rVV10		r ² SCAN + rVV10		
	(600,600)	(900,2k)	$b = 11.95$ (600,600) (900,2k)	$b = 12.3$ (900,2k)	
<i>7 hydrogen-bonded complexes</i>					
MAE	0.99	0.89	0.54	0.62	0.58
ME	0.99	0.89	0.54	0.62	0.58
<i>8 dispersion-bound complexes</i>					
MAE	0.42	0.22	0.14	0.18	0.18
ME	-0.11	-0.16	0.09	0.08	0.00
<i>7 mixed complexes</i>					
MAE	0.36	0.20	0.23	0.18	0.20
ME	-0.02	-0.06	-0.01	-0.02	-0.06
<i>Total</i>					
MAE	0.58	0.43	0.30	0.32	0.31
ME	0.27	0.21	0.20	0.22	0.17

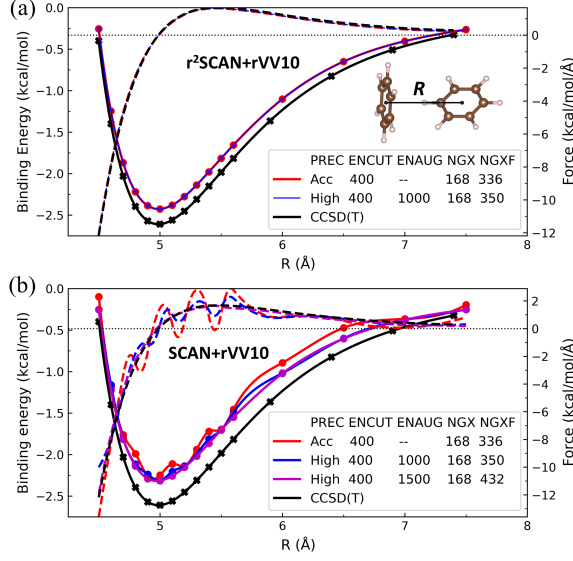


FIG. 2. The binding energy curves (solid lines) and forces (dashed lines) for the T configuration of benzene dimer from (a) $r^2\text{SCAN}+\text{rVV10}$ and (b) $\text{SCAN}+\text{rVV10}$ compared to the CCSD(T) results⁷⁸ as the reference, as a function of their separation R in Å. As in Ref. 75, forces are computed using a spline interpolation of the binding energy data.

cate for using different parameters in VV10- and rVV10-corrected DFAs; thus we recommend using $b = 12.3$ for $r^2\text{SCAN}+\text{rVV10}$, and $b = 11.95$ for $r^2\text{SCAN}+\text{rVV10}$.

A previous study⁷⁵ demonstrated that $\text{SCAN}+\text{rVV10}$ produces significant oscillations in the interaction energy and force curves of the benzene dimer, which persist even with a large energy cutoff. In this work, we consider the T benzene dimer and confirm that removing such oscillations requires denser real space grids. Specifically for VASP users, we recommend using a high ENAUG (~ 1500) at certain ENCUT with $\text{PREC}=\text{High}$, instead of increasing ENCUT with $\text{PREC}=\text{Accurate}$. The $r^2\text{SCAN}+\text{rVV10}$ binding energy and force curves don't show oscillations even with low accuracy settings, as shown in Fig. 2. However, $r^2\text{SCAN}$ as a meta-GGA is still much more complicated than LDA and PBE, and thus may still need dense real space grids for certain applications⁷⁷. To ensure stable convergence behavior, we recommend using dense real space grids ($\text{PREC}=\text{High}$; $\text{ENAUG}=1500$ or 2000) for SCAN-like metaGGA's and functionals based on them.

B. Layered materials

We also tested the predictions of $\text{SCAN}+\text{rVV10}$ and $r^2\text{SCAN}+\text{rVV10}$ for geometry and inter-layer binding properties for 28 layered materials (L28). As shown in Tables II and III, $r^2\text{SCAN}+\text{rVV10}$ more accurately predicts lattice constants than $\text{SCAN}+\text{rVV10}$ for this test set, and converges quicker with respect to plane-wave ba-

TABLE II. Unsigned layer-layer binding energy E_b in $\text{meV}/\text{\AA}^2$, lattice constants c and a in Å, for 28 layered materials (L28) from $\text{SCAN}+\text{rVV10}$ and $r^2\text{SCAN}+\text{rVV10}$. Mean deviations (MDs) and mean absolute deviations (MADs) are taken with respect to the RPA⁷² (an uncertain reference; see Table IV) for E_b , and experiment⁷⁰ for the lattice constants c and a . Table VIII in the Appendix presents values for each material in the set, the reference values, and values for other density functional approximations.

	$\text{SCAN}+\text{rVV10}$			$r^2\text{SCAN}+\text{rVV10}$		
	E_b	c	a	E_b	c	a
MAD	1.527	0.167	0.019	2.786	0.139	0.018
MD	0.476	0.132	-0.007	2.670	0.108	0.009

TABLE III. Convergence of lattice constants c and a in Å for 28 layered materials from $\text{SCAN}+\text{rVV10}$ and $r^2\text{SCAN}+\text{rVV10}$. Different (ENCUT, ENAUG) settings are presented; both values are in eV. Mean deviations (MDs) and mean absolute deviations (MADs) are taken with respect to the largest ENCUT, 800 eV, and ENAUG, 2000 eV, setting. $r^2\text{SCAN}+\text{rVV10}$ approaches its converged values more rapidly than does $\text{SCAN}+\text{rVV10}$. For the lattice parameters of each solid in the set, refer to Table IX in the Appendix.

	$\text{SCAN}+\text{rVV10}$				$r^2\text{SCAN}+\text{rVV10}$			
	(500,600)		(500,1k)		(500,600)		(500,1k)	
	c	a	c	a	c	a	c	a
MAD	0.024	0.002	0.010	0.001	0.009	0.000	0.008	0.000
MD	0.006	-0.001	-0.008	0.000	-0.007	0.000	-0.006	0.000

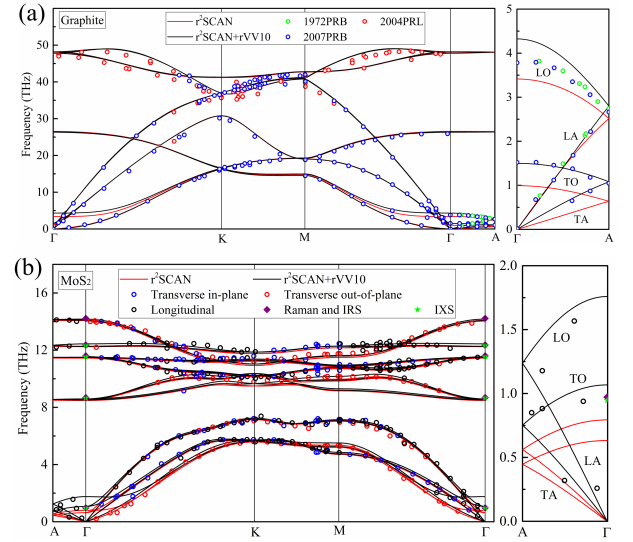


FIG. 3. Phonon dispersion in (a) graphite, (b) MoS₂, highlighting the improvements on the phonon branches along Γ -A (along the c -axis, or interlayer direction) from vdW corrections, compared with available experimental data from Refs. 79–81 for graphite and Refs. 82–85 for MoS₂. Calculations were performed at the relaxed lattice parameters. For an analogous figure using PBE and PBE-D4, see Fig. 5 of the Appendix.

TABLE IV. Unsigned layer-layer binding energy E_b in $\text{meV}/\text{\AA}^2$ of graphite, hexagonal boron nitride (h-BN), MoS_2 , TiS_2 and black phosphorous, calculated from SCAN+rVV10 and $\text{r}^2\text{SCAN+rVV10}$ compared with available data from experiments and other computational methods. A high-level, finite cluster CCSD(T) calculation⁸⁶ for bulk black phosphorous found its exfoliation energy to be $25.81 \text{ meV}/\text{\AA}^2$. We also report values for the rev-vdW-DF2⁸⁷ vdW-corrected GGA when available.

		Expt.	QMC	RPA	rev-vdW-DF2	SCAN + rVV10	$\text{r}^2\text{SCAN} + \text{rVV10}$
Graphite	Bulk	23.28 ± 1.91^{88}	22.91 ± 1.91^{89}	18.32^{90}	23.45^{32}	20.01	22.85
	Bilayer		13.51 ± 0.69^{91}			17.64	20.13
h-BN	Bulk			14.49^{72}	21.15^{32}	20.62	22.55
	Bilayer		15.02 ± 0.46^{92}			17.03	19.70
MoS_2	Bulk	34.33 ± 8.11^{93}		20.53^{72}	23.53^{32}	20.15	23.07
TiS_2	Bulk		27.2 ± 0.8^{94}	18.88^{72}	24.8^{94}	18.97	21.49
	Bilayer		24.9 ± 1.6^{94}		23.8^{94}	17.71	20.06
Black P	Bulk		22.4 ± 1.6^{95}			22.59	25.46
	Bilayer		16.6 ± 2.2^{95}			21.28	23.97

sis truncation and the size of the real space integration grid, the ENCUT and ENAUG settings in VASP respectively. This is clearly shown by the c lattice constants in Tables II and III. For values of the individual solids in the L28 set, refer to Tables VIII and IX of the Appendix.

SCAN+rVV10 and $\text{r}^2\text{SCAN+rVV10}$ predict much longer c lattice constants for PtSe_2 , WSe_2 , MoTe_2 , NbS_2 , NbSe_2 , and NbTe_2 than those found experimentally⁷⁰. We expect this may be due to the complicated electronic ground states of these materials, featuring charge density wave or superconductive phases^{96–98}, which were not considered in the present calculations. The effect of vdW functional corrections on these properties warrants further examination, but is beyond the scope of the current work.

To assess inter-layer binding energies for the L28 set in Table II, we must use RPA reference values⁷⁰, as those from more sophisticated methods [like the CCSD(T) references^{60,61,69} for S22] are unavailable. Select exceptions will be discussed further. While the RPA includes long-range vdW interactions⁹⁹, it lacks an accurate description of short-range correlation¹⁰⁰ and tends to underestimate C_6 vdW coefficients¹⁰¹. RPA may tend to underbind layered materials.

Table IV presents inter-layer binding energies for a few solids where high-level QMC^{89,91,92,94,95} and silver-standard RPA values are available. **No gold-standard correlated wavefunction calculations [such as CCSD(T)] for these solids have been undertaken at the time of writing.** The QMC and experimental benchmarks show that RPA underbinds bulk graphite, MoS_2 , and TiS_2 by 5-10 $\text{meV}/\text{\AA}^2$. SCAN+rVV10 and $\text{r}^2\text{SCAN+rVV10}$ are slightly more accurate than RPA for these three bulk materials, but overestimate the bilayer binding energies of graphite and MoS_2 . SCAN+rVV10 often predicts larger binding energies than the RPA, and $\text{r}^2\text{SCAN+rVV10}$ often predicts larger binding energies than SCAN+rVV10.

With these findings, we may tentatively say that $\text{r}^2\text{SCAN+rVV10}$ is more accurate than RPA and SCAN+rVV10 for layered materials, though further benchmark studies with expanded comparison to high

accuracy QMC calculations would be beneficial.

Alongside accurate static structural properties, dynamical lattice properties are also essential for materials design applications. We have recently shown that while SCAN gives accurate static structural properties, its accuracy for dynamical properties is limited by its numerical sensitivity, while r^2SCAN maintains good performance for both static and dynamical properties⁷⁷. With this in mind, phonon dispersion in graphite and MoS_2 are presented in Fig. 3. For both systems, our $\text{r}^2\text{SCAN+rVV10}$ results are in excellent agreement with the experimental data, especially for the lowest longitudinal acoustic (LA), longitudinal optical (LO), transverse acoustic (TA), and transverse optical (TO) phonon branches along the $\Gamma - A$ (interlayer or c -axis) direction. The calculated strengths of these branches are dominated by the inter-layer binding forces, and are thus sensitive to vdW corrections. Without the rVV10 correction, the uncorrected r^2SCAN severely underestimates these phonon branches.

TABLE V. Equilibrium lattice constants of PPTA, found by stress minimization within the VASP code. Computed and experimental values from Ref. 35 are included for comparison. Unlike other layered materials, the inter-layer or vdW direction in PPTA is the a axis.

	Methods	$a(\text{\AA})$	$b(\text{\AA})$	$c(\text{\AA})$	$\alpha(\text{deg})$
Ref. 35	Expt.	7.87	5.18	12.9	90
	SCAN	7.75	5.10	12.96	90.2
	SCAN+rVV10	7.21	5.08	12.95	90
This Work	SCAN	7.86	5.09	12.96	90.3
	SCAN+rVV10	7.43	5.10	12.96	90.1
	r^2SCAN	7.99	5.14	12.96	90.2
	$\text{r}^2\text{SCAN+rVV10}$	7.35	5.15	12.99	90.1

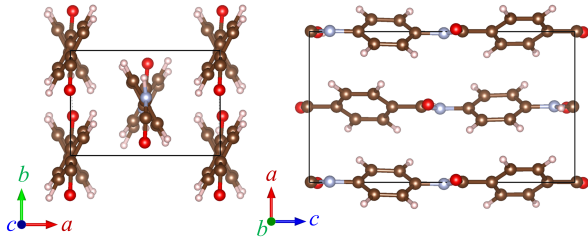


FIG. 4. PPTA crystal structure in view of the ab plane and ac plane. Carbon, nitrogen, oxygen, and hydrogen atoms are rendered in brown, gray, red, and white, respectively.

C. Complex materials: PPTA

Last, we present calculations for poly(*p*-phenylene terephthalamide) (PPTA), a layered material that is challenging for standard DFAs. PPTA, as shown in Fig. 4, is primarily vdW-bonded along its a -axis, hydrogen-bonded along its b -axis, and covalently bonded along its c -axis³⁵ – a robust test for general-purpose DFAs. Table V presents the equilibrium structure of PPTA determined by SCAN, r^2 SCAN, and their rVV10 variants. The SCAN+rVV10 lattice parameters computed in Ref. 35 (and included in Table V) used an older version of VASP where the rVV10 stress tensor elements were not correctly computed⁶⁸. The calculations performed here use a corrected version of VASP and different computational parameters than those of Ref. 35. We used a $6 \times 9 \times 4$ \mathbf{k} -point grid (corresponding to \mathbf{k} -point spacing of 0.15 \AA^{-1}) and a plane-wave cutoff of 900 eV, whereas Ref. 35 used a $6 \times 6 \times 6$ \mathbf{k} -point grid and plane-wave cutoff of 520 eV. The number of grid points along c is well-converged at 4 points.

The effects of incorrect stress tensor elements are pronounced: the minima in the energy curves as a function of strained lattice parameters in Fig. 2 of Ref. 35 do not coincide with the values in their Table 1. As their relaxed values of b and c for SCAN and SCAN+rVV10 are similar to ours, we refit their energy data as a function of a at fixed $b = 5.10 \text{ \AA}$ and $c = 12.96 \text{ \AA}$ for SCAN, and $b = 5.08 \text{ \AA}$ and $c = 12.95 \text{ \AA}$ for SCAN+rVV10. We find $a = 7.92 \text{ \AA}$ for SCAN, and $a = 7.42 \text{ \AA}$ for SCAN+rVV10, more comparable to our values in Table V.

Although the a axis is the vdW-bonded axis in PPTA, the uncorrected SCAN provides the most correct description of inter-layer binding in PPTA. SCAN+rVV10 and r^2 SCAN+rVV10 severely overbind along the a axis, and do not provide substantive corrections to the parent meta-GGA along the b and c axes.

IV. CONCLUSIONS

We have optimized the r^2 SCAN+rVV10 vdW density functional and tested its performance against both molecular (S22) and layered material databases. The global b parameter is adjusted to 11.95 by fitting to the Ar dimer binding energy curve. This is somewhat smaller than the VV10 $b = 12.3$ parameter in Ref. 19, and considerably smaller than the 15.7 used in SCAN+rVV10, suggesting that r^2 SCAN requires more vdW correction than SCAN. With $b = 11.95$, r^2 SCAN+rVV10 is more accurate than SCAN+rVV10 for the S22 binding energy database, and is competitive with the original rVV10 functional.

For the L28 layered material data set, r^2 SCAN+rVV10 also outperforms SCAN+rVV10 in accuracy and efficiency for lattice constants predictions. For inter-layer binding energies, r^2 SCAN+rVV10 shows stronger binding than SCAN+rVV10, which suggests over-binding when compared with RPA and available QMC benchmarks. In extended systems like layered bulk materials and bilayers, important many-atom/screening effects may be present in QMC that are missing in r^2 SCAN+rVV10. However, r^2 SCAN+rVV10 accurately accounts for phonon dispersion in layered bulk materials, improving substantially over r^2 SCAN. The study of PPTA demonstrates that care must be taken when using vdW-corrected DFAs. The uncorrected parent DFA may sufficiently describe intermediate vdW interactions, leading to overbinding when the rVV10 correction is included. We also highlight that r^2 SCAN+rVV10 inherits the good numerical stability of r^2 SCAN, and recommend r^2 SCAN+rVV10 as a versatile vdW XC functional.

ACKNOWLEDGMENTS

J.N. and M.K. acknowledge the support of the U.S. Department of Energy (DOE), Office of Science (OS), Basic Energy Sciences (BES), Grant No. DE-SC0014208. J.S. acknowledges the support of the U.S. National Science Foundation (NSF) under Grant No. DMR-2042618. J.W.F. acknowledges support from DOE grant DE-SC0019350. A.D.K. acknowledges the support of the U.S. DOE, Office of Science, BES, through Grant No. DE-SC0012575 to the Energy Frontier Research Center: Center for Complex Materials from First Principles, and also support from Temple University. J.P.P. acknowledges the support of the US NSF under Grant No. DMR-1939528. We thank J. Yu for discussions on PPTA.

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Appendix: Additional data sets and figures

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TABLE VI. Mean errors (ME, kcal/mol), mean absolute errors (MAE, kcal/mol), mean percentage errors (MPE), and mean absolute percentage errors (MAPE) in the unsigned interaction energies of the S22 data set, taken with respect to CCSD(T) results⁶⁹. Different (ENCUT, ENAUG) settings (described in Section III A) are tested for r²SCAN+rVV10 and SCAN+rVV10; both values are in eV. Users who need less accuracy can use lower settings. **For a concise presentation of this data, refer to Table I.** Table VII in the Appendix presents interaction energies for each molecule in the S22 set, the CCSD(T) reference values, as well as values for other density functional approximations.

	SCAN+rVV10			r ² SCAN+rVV10			
	(600, 600)	(600, 1000)	(900, 2000)	(600, 600)	$b = 11.95$ (600, 1000)	(900, 2000)	$b = 12.3$ (900, 2000)
<i>7 hydrogen-bonded complexes</i>							
MAE	0.99	0.95	0.89	0.54	0.56	0.62	0.58
ME	0.99	0.95	0.89	0.54	0.56	0.62	0.58
MAPE	7.78	7.54	6.64	3.90	3.99	4.38	4.11
MPE	7.78	7.54	6.64	3.90	3.99	4.38	4.11
<i>8 dispersion-bound complexes</i>							
MAE	0.42	0.17	0.22	0.14	0.13	0.18	0.18
ME	-0.11	-0.11	-0.16	0.09	0.08	0.08	0.00
MAPE	14.00	6.17	6.65	3.01	2.56	3.65	4.66
MPE	-3.93	-2.11	-6.02	0.14	-0.10	-1.06	-3.00
<i>7 mixed complexes</i>							
MAE	0.36	0.31	0.20	0.23	0.23	0.18	0.20
ME	-0.02	-0.04	-0.06	-0.01	-0.03	-0.02	-0.06
MAPE	10.32	8.37	5.69	6.44	6.32	5.32	5.54
MPE	1.88	1.32	-0.69	1.75	1.24	0.64	-0.33
<i>Total</i>							
MAE	0.58	0.46	0.43	0.30	0.30	0.32	0.31
ME	0.27	0.25	0.21	0.20	0.20	0.22	0.17
MAPE	10.85	7.31	6.34	4.39	4.21	4.42	4.76
MPE	1.65	2.05	-0.29	1.85	1.63	1.21	0.11

TABLE VII. Positive interaction **energy errors (approximate minus the CCSD(T) reference)**, in kcal/mol, for the molecular dimers in the S22 data set from PBE, rVV10, vdW-DF2 (numerical results from Ref. 24), SCAN results from Ref. 32, SCAN+rVV10 and r²SCAN+rVV10 with respect to the CCSD(T) results⁶⁹. Different (ENCUT, ENAUG) settings are tested for r²SCAN+rVV10 and SCAN+rVV10; both values are in eV. **Absolute errors that are greater than twice the corresponding MAD are bold-faced.**

	CCSD(T)	PBE	rVV10	vdW-DF2	SCAN	r ² SCAN+rVV10			SCAN+rVV10		
						(600,600)	(600,1000)	(900,2000)	(600,600)	(600,1000)	(900,2000)
7 hydrogen-bound complexes											
NH ₃ dimer (C2h)	3.13	-0.32	0.28	-0.16	-0.01	0.04	0.05	0.03	0.28	0.29	0.15
H ₂ O dimer (Cs)	4.99	-0.05	0.52	-0.21	0.44	0.34	0.35	0.39	0.55	0.56	0.56
Formic acid dimer (C2h)	18.75	-0.51	1.22	-1.98	2.18	1.84	1.87	2.07	3.00	2.86	2.77
Formamide dimer (C2h)	16.06	-1.28	0.66	-1.63	0.48	0.35	0.39	0.60	0.93	0.92	0.99
Uracil dimer (C2h)	20.64	-2.10	0.48	-1.95	-0.15	0.27	0.32	0.36	0.24	0.64	0.62
2-pyridone-2-aminopyridine (C1)	16.93	-1.56	1.13	-1.56	-0.08	0.66	0.68	0.68	0.58	0.88	0.88
Adenine-thymine WC (C1)	16.66	-2.31	0.76	-1.92	-0.67	0.30	0.26	0.21	1.37	0.51	0.25
MAE [REF CCSD(T)]		1.16	0.72	1.35	0.57	0.54	0.56	0.62	0.99	0.95	0.89
ME [REF CCSD(T)]		-1.16	0.72	-1.35	0.31	0.54	0.56	0.62	0.99	0.95	0.89
STD DEV [REF CCSD(T)]		0.82	0.32	0.75	0.84	0.56	0.56	0.63	0.90	0.80	0.82
MAE [REF (900,2000)]						0.09	0.07	0.00	0.16	0.05	0.00
8 dispersion-bound complexes											
CH ₄ dimer (D3d)	0.53	-0.43	-0.04	0.15	-0.18	-0.02	-0.01	-0.00	-0.14	-0.03	-0.01
C ₂ H ₄ dimer (D2d)	1.47	-1.14	-0.06	-0.15	-0.45	-0.06	-0.06	-0.11	-0.34	-0.16	-0.09
Benzene-CH ₄ (C3)	1.45	-1.40	-0.01	-0.16	-0.58	-0.00	-0.03	-0.09	0.23	0.21	-0.22
Benzene dimer (C2h)	2.65	-4.50	0.07	-0.50	-1.58	0.12	0.05	0.02	-0.10	0.05	-0.24
Pyrazine dimer (Cs)	4.25	-4.93	-0.22	-0.96	-1.60	-0.11	-0.10	-0.02	1.03	-0.30	-0.22
Uracil dimer (C2)	9.80	-7.07	-0.08	-1.04	-1.84	0.45	0.50	0.62	-1.32	-0.26	0.25
Indole-benzene (C1)	4.52	-6.69	0.01	-1.08	-2.40	0.05	0.00	-0.18	-0.22	-0.29	-0.56
Adenine-thymine (C1)	11.73	-10.31	-0.31	-2.15	-3.08	0.31	0.31	0.36	-0.01	-0.07	-0.16
MAE [REF CCSD(T)]		4.56	0.10	0.78	1.47	0.14	0.13	0.18	0.42	0.17	0.22
ME [REF CCSD(T)]		-4.56	-0.08	-0.74	-1.47	0.09	0.08	0.08	-0.11	-0.11	-0.16
STD DEV [REF CCSD(T)]		3.22	0.12	0.69	0.94	0.18	0.20	0.26	0.61	0.17	0.21
MAE [REF (900,2000)]						0.09	0.07	0.00	0.52	0.21	0.00
7 mixed complexes											
C ₂ H ₄ -C ₂ H ₂ (C2v)	1.50	-0.32	0.17	0.03	-0.16	0.07	0.06	0.05	0.24	0.06	0.06
Benzene-H ₂ O (Cs)	3.27	-1.25	0.04	-0.48	0.00	0.43	0.40	0.39	0.58	0.54	0.34
Benzene-NH ₃ (Cs)	2.31	-1.38	-0.04	-0.32	-0.32	0.21	0.20	0.13	0.14	0.26	0.05
Benzene-HCN (Cs)	4.54	-1.71	-0.27	-0.99	-0.48	0.07	0.06	-0.00	-0.07	0.09	0.04
Benzene dimer (C2v)	2.72	-2.59	-0.17	-0.66	-1.24	-0.17	-0.19	-0.24	-0.30	-0.26	-0.33
Indole-benzene (Cs)	5.63	-3.57	-0.35	-1.43	-1.56	-0.19	-0.19	-0.25	-0.94	-0.46	-0.47
MAE [REF CCSD(T)]		1.80	0.17	0.65	0.63	0.19	0.18	0.18	0.38	0.28	0.22
ME [REF CCSD(T)]		-1.80	-0.10	-0.64	-0.62	0.07	0.06	0.01	-0.06	0.04	-0.05
STD DEV [REF CCSD(T)]		1.03	0.18	0.47	0.57	0.21	0.21	0.22	0.48	0.33	0.27
MAE [REF (900,2000)]						0.05	0.03	0.00	0.11	0.09	0.00
Total											
MAE [REF CCSD(T)]		2.67	0.32	0.94	0.94	0.30	0.30	0.32	0.58	0.46	0.43
ME [REF CCSD(T)]		-2.67	0.17	-0.92	-0.66	0.20	0.20	0.22	0.27	0.25	0.21
STD DEV [REF CCSD(T)]		2.55	0.43	0.71	1.09	0.44	0.45	0.49	0.84	0.70	0.68
MAE [REF (900,2000)]						0.10	0.08	0.00	0.36	0.15	0.00

TABLE VIII. Positive layer-layer binding energy E_b in $\text{meV}/\text{\AA}^2$, lattice constants c and a in \AA for 28 layered materials (L28 test set) from SCAN+rVV10 and $r^2\text{SCAN}+\text{rVV10}$. The reference values are E_b from RPA calculations⁷² and lattice constants c and a from experiment⁷⁰. ΔE_b , Δa , and Δc are the deviations in the interlayer binding energy, a lattice parameter, and c lattice parameter, respectively. The mean deviations (MDs), mean absolute deviations (MADs), and standard deviations (STD DEVs) are also presented. Absolute errors that are greater than twice the corresponding MAD are **bold-faced**.

	RPA E_b	Expt. c a		rev-vdW-DF2 ΔE_b Δc Δa			SCAN ΔE_b Δc Δa			SCAN+rVV10 ΔE_b Δc Δa			$r^2\text{SCAN}+\text{rVV10}$ ΔE_b Δc Δa		
h-BN	14.49	6.54	2.51	6.66	0.00	0.00	-7.20	0.30	-0.01	4.96	0.00	-0.01	8.00	-0.04	-0.01
Graphite	18.32	6.70	2.46	5.13	-0.11	0.00	-10.40	0.16	-0.01	1.63	-0.05	-0.01	4.53	-0.07	-0.00
HfS ₂	16.13	5.84	3.63	3.77	-0.01	-0.02	-10.94	0.20	0.00	-0.09	0.04	-0.02	2.09	0.04	-0.01
HfSe ₂	17.09	6.16	3.75	3.33	0.02	-0.01	-11.66	0.24	0.00	-0.82	0.06	-0.01	1.30	0.05	-0.00
HfTe ₂	18.68	6.65	3.96	4.48	0.04	-0.03	-11.68	0.28	0.01	-0.50	0.13	-0.01	1.37	0.13	0.02
MoS ₂	20.53	12.30	3.16	3.00	0.04	0.01	-14.86	0.52	0.01	-0.32	0.18	0.01	2.71	0.13	0.02
MoSe ₂	19.63	12.93	3.29	3.45	0.12	0.01	-14.01	0.61	0.02	0.08	0.24	0.01	2.91	0.19	0.02
MoTe ₂	20.80	13.97	3.52	3.30	0.11	0.01	-13.95	0.66	0.00	-0.18	0.30	-0.01	2.22	0.25	0.03
NbS ₂	17.58	17.91	3.33	7.58	0.24	-0.01	-10.65	0.93	0.01	2.94	0.46	0.00	5.65	0.40	0.01
NbSe ₂	19.57	12.55	3.44	7.82	-0.06	0.01	-11.93	0.50	0.03	0.45	0.49	0.02	3.04	0.44	0.02
NbTe ₂	23.03	6.61	3.68	4.14	0.20	-0.01	-14.37	0.57	-0.02	-1.24	0.33	-0.03	1.03	0.27	0.02
PbO	20.25	5.00	3.96	-3.30	0.05	0.07	-8.43	0.10	0.03	3.08	-0.07	0.03	1.40	0.01	0.03
PdTe ₂	40.17	5.11	4.02	3.44	0.05	0.05	-14.98	-0.07	0.03	2.25	-0.08	0.02	-0.25	0.06	0.04
PtS ₂	20.55	5.04	3.54	2.85	-0.13	0.05	-15.14	0.50	-0.01	-1.39	0.17	-0.01	1.46	0.09	0.01
PtSe ₂	19.05	5.11	3.73	5.86	-0.13	0.06	-13.14	0.62	-0.04	0.34	0.29	-0.03	3.06	0.20	0.00
TaS ₂	17.68	5.90	3.36	8.29	0.00	-0.01	-10.30	0.24	0.00	3.74	0.06	-0.01	6.43	0.05	0.01
TaSe ₂	19.44	6.27	3.48	6.37	0.02	-0.01	-12.12	0.25	0.00	2.69	0.06	-0.01	5.24	0.04	0.01
TiS ₂	18.88	5.90	3.41	5.47	-0.25	-0.02	-11.98	-0.02	0.01	0.14	-0.14	0.00	2.66	-0.16	0.00
TiSe ₂	17.39	6.27	3.54	7.38	-0.29	-0.02	-10.50	0.01	0.01	1.42	-0.16	0.00	3.86	-0.17	0.01
TiTe ₂	19.76	6.50	3.78	7.11	0.02	-0.03	-12.06	0.32	-0.01	0.19	0.15	-0.02	2.35	0.11	0.01
VS ₂	25.61	5.75	3.22	1.17	0.06	-0.05	-18.40	0.32	-0.03	-4.30	0.01	0.03	-1.37	-0.00	0.04
VSe ₂	22.26	6.11	3.36	3.26	0.05	-0.04	-15.62	0.38	-0.03	-2.64	0.08	0.04	0.14	0.03	0.05
VTe ₂	20.39	6.58	3.64	6.27	0.01	-0.05	-12.89	0.55	-0.09	-0.56	0.10	0.02	1.35	0.01	0.06
WS ₂	20.24	12.32	3.15	3.69	0.09	0.02	-12.15	0.32	0.03	0.56	0.21	0.01	3.60	0.16	0.02
WSe ₂	19.98	12.96	3.28	3.45	0.13	0.02	-13.29	0.44	0.03	0.25	0.25	0.01	3.06	0.22	0.03
ZrS ₂	16.98	5.81	3.66	3.09	0.02	-0.01	-11.55	0.21	0.03	-0.85	0.06	0.02	1.35	0.05	0.01
ZrSe ₂	18.53	6.13	3.77	2.55	0.02	0.00	-12.66	0.24	0.03	-1.84	0.08	0.02	0.34	0.06	0.02
ZrTe ₂	16.34	6.66	3.95	8.84	0.01	-0.02	-8.33	0.26	0.05	3.33	0.08	0.03	5.23	0.07	0.05
MD				4.59	0.01	-0.00	-12.33	0.34	0.00	0.48	0.12	0.00	2.67	0.09	0.02
MAD				4.82	0.08	0.02	12.33	0.35	0.02	1.53	0.15	0.02	2.79	0.13	0.02
STD DEV				2.50	0.11	0.03	2.36	0.22	0.03	2.01	0.16	0.02	2.08	0.14	0.02

TABLE IX. Lattice constants c and a in Å for 28 layered materials (**L28 data set**) from SCAN+rVV10 and r²SCAN+rVV10. **Deviations are reported under Δc and Δa columns.** Different (ENCUT, ENAUG) settings are presented; both values are in eV. The experimental values of c and a are included for comparison⁷⁰. Mean **deviations (MDs)** and mean **absolute deviations (MADs)** are taken with respect to the largest ENCUT, 800 eV, and ENAUG, 2000 eV, setting. r²SCAN+rVV10 approaches its converged values more rapidly than does SCAN+rVV10.

	Expt.		SCAN+rVV10						r ² SCAN+rVV10					
			(500,600)		(500,1000)		(800,2000)		(500,600)		(500,1000)		(800,2000)	
	c	a	Δc	Δa	Δc	Δa	c	a	Δc	Δa	Δc	Δa	c	a
h-BN	6.54	2.51	-0.08	-0.00	-0.07	-0.00	6.54	2.50	-0.07	-0.00	-0.06	-0.00	6.50	2.50
Graphite	6.70	2.46	0.04	0.00	0.02	0.00	6.65	2.45	0.03	0.00	0.03	0.00	6.63	2.46
HfS ₂	5.84	3.63	0.04	0.00	-0.01	-0.00	5.87	3.61	-0.00	-0.00	-0.00	-0.00	5.88	3.62
HfSe ₂	6.16	3.75	-0.01	-0.00	0.00	0.00	6.22	3.74	0.00	0.00	-0.00	-0.00	6.21	3.75
HfTe ₂	6.65	3.96	-0.01	-0.00	0.00	0.00	6.79	3.95	-0.00	0.00	-0.00	-0.00	6.78	3.98
MoS ₂	12.30	3.16	0.02	-0.00	-0.00	-0.00	12.47	3.17	-0.01	-0.01	-0.01	-0.00	12.43	3.18
MoSe ₂	12.93	3.29	0.02	-0.00	0.00	-0.00	13.17	3.30	0.00	-0.00	0.00	-0.00	13.12	3.31
MoTe ₂	13.97	3.52	0.04	-0.00	0.00	-0.00	14.26	3.51	-0.01	0.00	-0.01	-0.00	14.22	3.55
NbS ₂	17.91	3.33	-0.01	-0.00	-0.03	-0.00	18.34	3.33	-0.02	0.00	-0.02	-0.00	18.31	3.34
NbSe ₂	12.55	3.44	0.00	-0.00	-0.01	-0.00	13.01	3.46	-0.01	-0.00	-0.01	-0.00	12.99	3.46
NbTe ₂	6.61	3.68	0.00	-0.00	0.00	-0.00	6.95	3.65	-0.00	0.00	-0.00	-0.00	6.88	3.70
PbO	5.00	3.96	-0.04	0.01	-0.02	-0.00	4.94	3.99	-0.02	-0.00	-0.02	-0.00	5.01	3.99
PdTe ₂	5.11	4.02	0.00	-0.00	0.00	-0.00	5.03	4.04	-0.00	0.00	-0.00	-0.00	5.17	4.06
PtS ₂	5.04	3.54	0.06	-0.00	-0.01	0.00	5.19	3.53	-0.01	-0.00	-0.01	-0.00	5.13	3.55
PtSe ₂	5.11	3.73	-0.01	0.00	-0.01	0.00	5.40	3.70	-0.00	-0.00	-0.01	0.00	5.31	3.73
TaS ₂	5.90	3.36	-0.03	-0.00	-0.01	-0.00	5.96	3.35	-0.00	0.00	-0.00	-0.00	5.95	3.37
TaSe ₂	6.27	3.48	-0.01	-0.00	0.00	-0.00	6.34	3.47	0.00	-0.00	0.00	0.00	6.31	3.49
TiS ₂	5.90	3.41	0.00	0.00	-0.01	-0.00	5.77	3.41	-0.00	-0.00	-0.01	-0.00	5.74	3.41
TiSe ₂	6.27	3.54	0.02	-0.01	-0.01	0.00	6.12	3.55	-0.01	0.00	-0.01	-0.00	6.10	3.55
TiTe ₂	6.50	3.78	0.01	-0.00	0.00	-0.00	6.64	3.77	-0.01	-0.00	-0.00	-0.00	6.61	3.79
VS ₂	5.75	3.22	0.05	-0.00	-0.01	-0.00	5.76	3.25	0.00	0.00	-0.01	-0.00	5.75	3.26
VSe ₂	6.11	3.36	-0.02	-0.00	0.00	-0.00	6.19	3.40	0.00	-0.00	0.00	-0.00	6.14	3.41
VTe ₂	6.58	3.64	0.07	-0.01	-0.05	0.02	6.68	3.66	-0.02	-0.00	-0.01	0.00	6.59	3.70
WS ₂	12.32	3.15	0.01	-0.00	-0.01	-0.00	12.51	3.16	-0.01	-0.00	-0.01	-0.00	12.48	3.17
WSe ₂	12.96	3.28	-0.02	0.00	-0.01	-0.00	13.22	3.29	-0.00	0.00	-0.01	-0.00	13.18	3.31
ZrS ₂	5.81	3.66	0.01	-0.00	-0.01	-0.00	5.88	3.68	-0.00	-0.00	-0.00	-0.00	5.86	3.67
ZrSe ₂	6.13	3.77	-0.01	-0.00	0.00	0.00	6.21	3.79	0.00	-0.00	0.00	0.00	6.19	3.79
ZrTe ₂	6.66	3.95	0.02	0.00	0.00	0.00	6.74	3.98	-0.00	0.00	-0.00	-0.00	6.73	4.00
MAD			0.024	0.002	0.010	0.001	0.000	0.000	0.009	0.003	0.008	0.000	0.000	0.000
MD			0.006	-0.001	-0.008	0.000	0.000	0.000	-0.007	-0.001	-0.006	-0.000	0.000	0.000
STD DEV			0.032	0.003	0.017	0.003	0.000	0.000	0.015	0.003	0.013	0.000	0.000	0.000

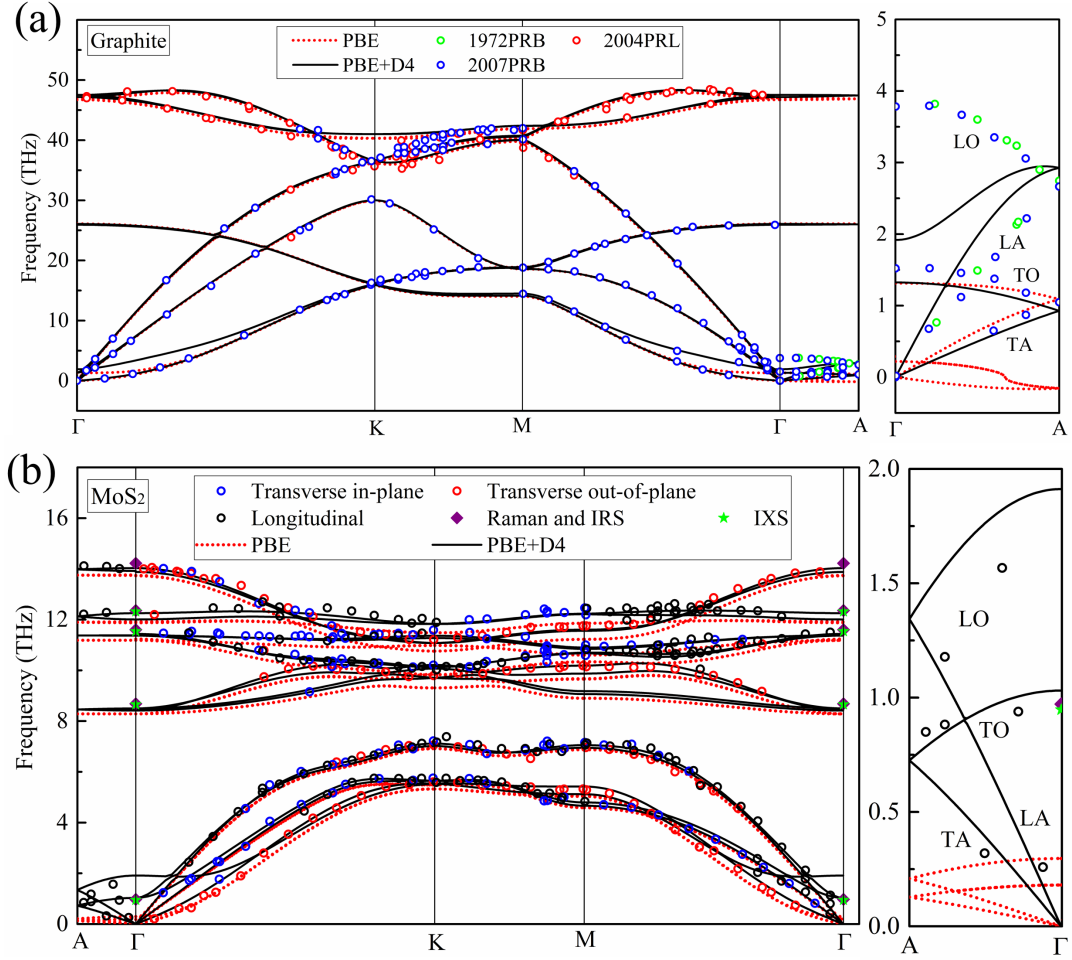


FIG. 5. Phonon dispersion in graphite and MoS₂ analogous to Fig. 3, but using PBE⁵⁸ and PBE-D4¹⁸ instead of r²SCAN. Just as for r²SCAN, adding a dispersion correction to PBE produces a more realistic phonon dispersion, especially along the inter-layer direction A- Γ . In MoS₂, PBE-D4 is in good accord with available experimental phonon dispersion data, however r²SCAN+rVV10 provides a more realistic description of phonons in graphite along the inter-layer direction.

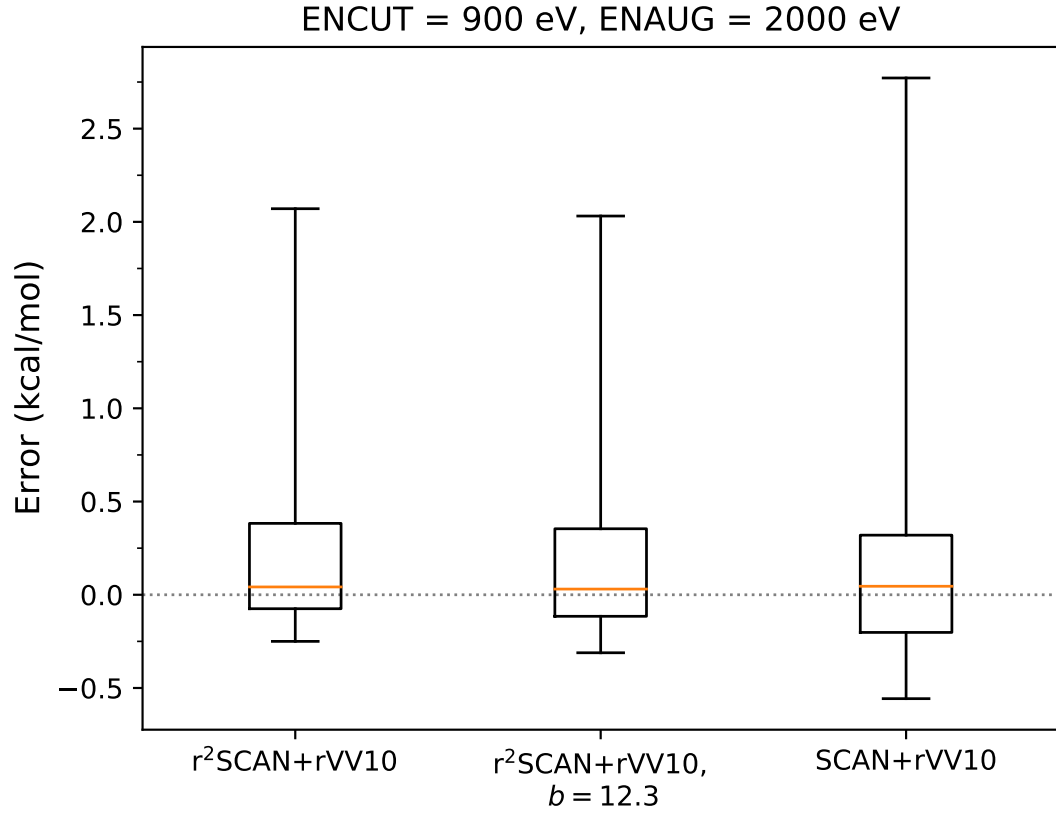


FIG. 6. Box and whisker plot of the S22 errors (kcal/mol) for r^2 SCAN+rVV10 with the presently-fitted value $b = 11.95$, with the VV10-fitted $b = 12.3$, and SCAN+rVV10. See Tables I and VII for tabulated errors.

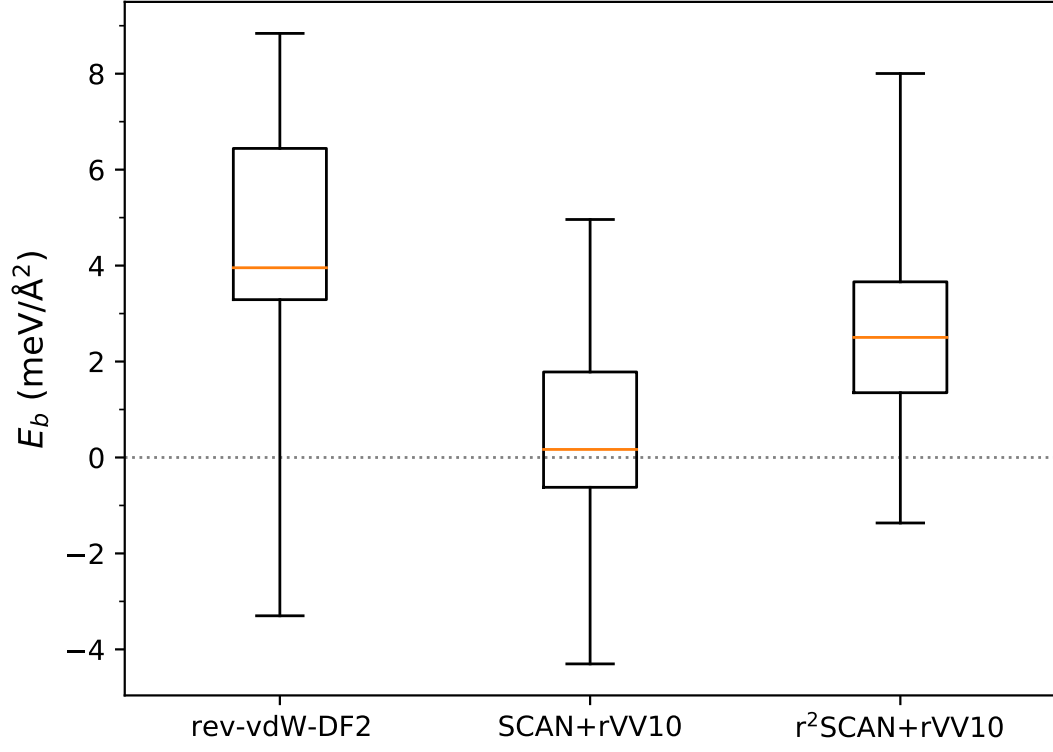


FIG. 7. Box and whisker plot of the L28 set binding energy E_b errors ($\text{meV}/\text{\AA}^2$) for rev-vdW-DF2, $r^2\text{SCAN+rVV10}$ with the presently-fitted value $b = 11.95$, and SCAN+rVV10. See Tables II and VIII for tabulated errors.

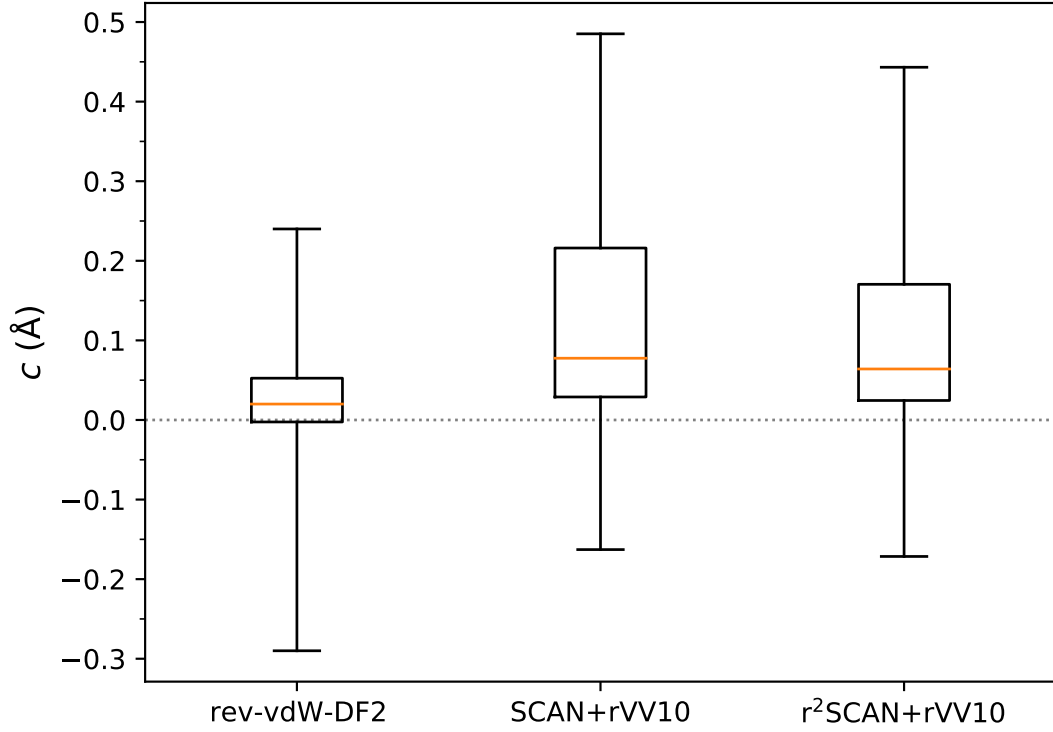


FIG. 8. Box and whisker plot of the L28 set out-of-plane lattice constant c errors (\AA) for rev-vdW-DF2, $r^2\text{SCAN+rVV10}$ with the presently-fitted value $b = 11.95$, and SCAN+rVV10. See Tables II and VIII for tabulated errors.

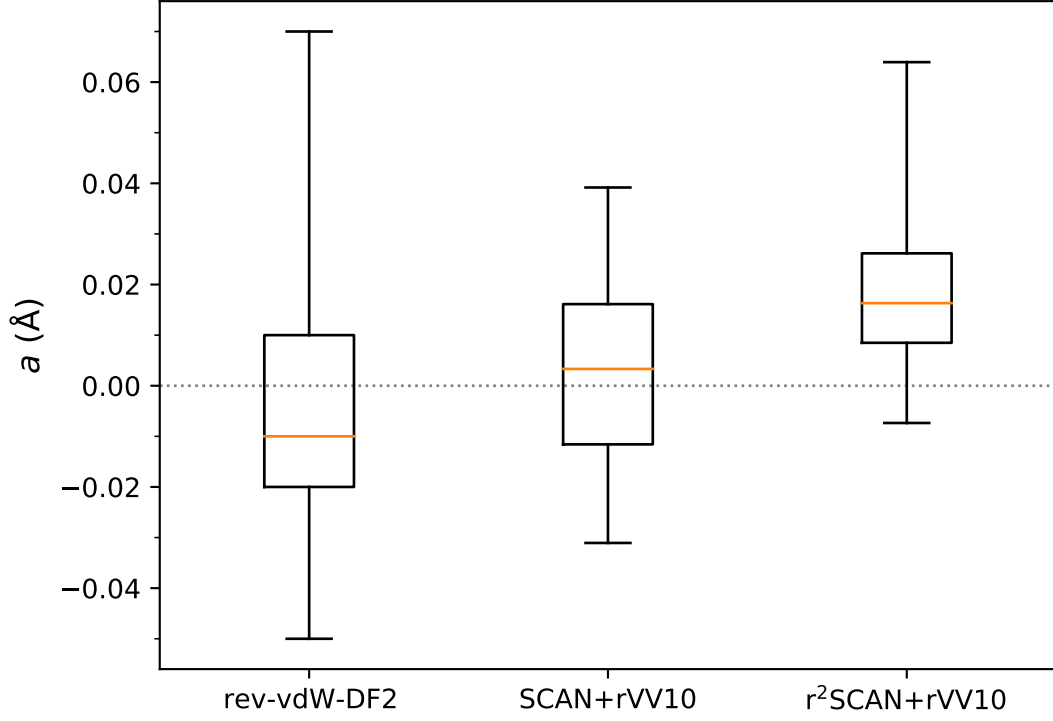


FIG. 9. Box and whisker plot of the L28 set in-plane lattice constant a errors (Å) for rev-vdW-DF2, r^2 SCAN+rVV10 with the presently-fitted value $b = 11.95$, and SCAN+rVV10. See Tables II and VIII for tabulated errors.